

Notice of References Cited

Application No.

08/843,124

Applicant(s)

Kawase, Tatsumi

Examiner

Evelyn Defillo

Group/Art Unit

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U.S. PATENT DOCUMENTS

*		DOCUMENT NO.	DATE	NAME	CLASS	SUBCLASS
A		5515810	5/14/96	Yamashita	117	17
B		5131975	7/21/92	Bourret - Courchesne	117	953
C						
D						
E						
F						
G						
H						
I						
J						
K						
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M						

FOREIGN PATENT DOCUMENTS

*		DOCUMENT NO.	DATE	COUNTRY	NAME	CLASS	SUBCLASS
N							
O							
P							
Q							
R							
S							
T							

NON-PATENT DOCUMENTS

*		DOCUMENT (Including Author, Title, Source, and Pertinent Pages)	DATE
U		"Low dislocation density and low residual strain semi insulating GaAs grown by vertical boat method". Kawase, T. (1996) Gpn1	—
V			
W			
X			

* A copy of this reference is not being furnished with this Office action.
(See Manual of Patent Examining Procedure, Section 707.05(a).)